



PJQ4441P-AU

40V P-Channel Enhancement Mode MOSFET

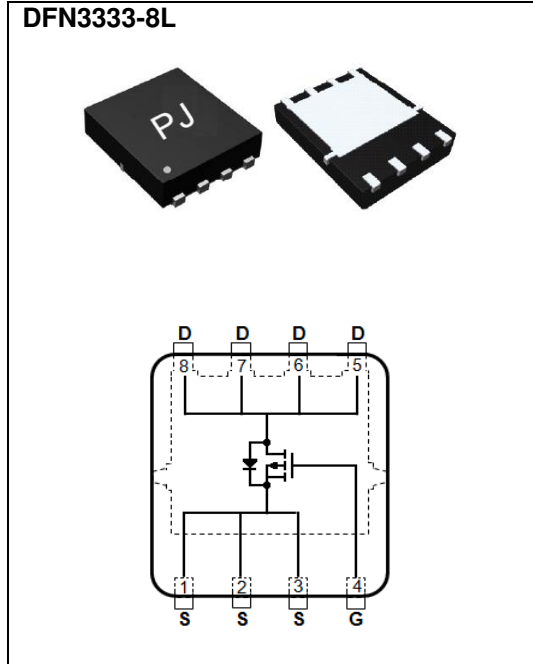
Voltage -40 V **Current** -44 A

Features

- $R_{DS(ON)}$, $V_{GS}@-10V$, $I_D@-10A < 17m\Omega$
- $R_{DS(ON)}$, $V_{GS}@-4.5V$, $I_D@-8A < 25m\Omega$
- Advanced Trench Process Technology
- High density cell design for ultralow on-resistance
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : DFN3333-8L Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight : 0.001 ounces, 0.03 grams



Maximum Ratings and Thermal Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| PARAMETER | | SYMBOL | LIMIT | UNITS |
|--|---------------------|-----------------|----------|--------------|
| Drain-Source Voltage | | V_{DS} | -40 | V |
| Gate-Source Voltage | | V_{GS} | ± 20 | |
| Continuous Drain Current ^(Note 4) | $T_C=25^\circ C$ | I_D | -44 | A |
| | $T_C=100^\circ C$ | | -28 | |
| Pulsed Drain Current ^(Note 1) | $T_C=25^\circ C$ | I_{DM} | -135 | |
| Power Dissipation | $T_C=25^\circ C$ | P_D | 59.5 | W |
| | $T_C=100^\circ C$ | | 24 | |
| Continuous Drain Current ^(Note 4) | $T_A=25^\circ C$ | I_D | -8.5 | A |
| | $T_A=70^\circ C$ | | -7 | |
| Power Dissipation | $T_A=25^\circ C$ | P_D | 2 | W |
| | $T_A=70^\circ C$ | | 1.3 | |
| Operating Junction and Storage Temperature Range | | T_J, T_{STG} | -55~150 | $^\circ C$ |
| Typical Thermal Resistance ^(Note 4,5) | Junction to Case | $R_{\theta JC}$ | 2.1 | $^\circ C/W$ |
| | Junction to Ambient | $R_{\theta JA}$ | 62.5 | |

- Limited only By Maximum Junction Temperature



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Electrical Characteristics (T_A=25°C unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNITS |
|---|---------------------|--|------|------|------|-------|
| Static | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V, I _D =-250uA | -40 | - | - | V |
| Gate Threshold Voltage | V _{GS(th)} | V _{DS} =V _{GS} , I _D =-250uA | -1 | -1.6 | -2.5 | |
| Drain-Source On-State Resistance | R _{DS(on)} | V _{GS} =-10V, I _D =-10A | - | 14 | 17 | mΩ |
| | | V _{GS} =-4.5V, I _D =-8A | - | 20 | 25 | |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =-40V, V _{GS} =0V | - | - | -1 | uA |
| Gate-Source Leakage Current | I _{GSS} | V _{GS} =±20V, V _{DS} =0V | - | - | ±100 | nA |
| Dynamic (Note 6) | | | | | | |
| Total Gate Charge | Q _g | V _{DS} =-32V, I _D =-10A, V _{GS} =-4.5V (Note 1,2) | - | 19 | - | nC |
| Gate-Source Charge | Q _{gs} | | - | 5.3 | - | |
| Gate-Drain Charge | Q _{gd} | | - | 6.6 | - | |
| Input Capacitance | C _{iss} | V _{DS} =-25V, V _{GS} =0V, f=1MHZ | - | 2030 | - | pF |
| Output Capacitance | C _{oss} | | - | 190 | - | |
| Reverse Transfer Capacitance | C _{rss} | | - | 139 | - | |
| Turn-On Delay Time | t _{d(on)} | V _{DS} =-20V, I _D =-1A, V _{GS} =-10V, R _G =6Ω (Note 1,2) | - | 8.6 | - | ns |
| Turn-On Rise Time | t _r | | - | 9.6 | - | |
| Turn-Off Delay Time | t _{d(off)} | | - | 77 | - | |
| Turn-Off Fall Time | t _f | | - | 39 | - | |
| Drain-Source Diode | | | | | | |
| Maximum Continuous Drain-Source Diode Forward Current | I _S | --- | - | - | -44 | A |
| Diode Forward Voltage | V _{SD} | I _S =-1A, V _{GS} =0V | - | -0.7 | -1 | V |

NOTES :

1. Pulse width ≤ 300us, Duty cycle ≤ 2%.
2. Essentially independent of operating temperature typical characteristics.
3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J = 25°C.
4. The maximum current rating is package limited.
5. R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.



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TYPICAL CHARACTERISTIC CURVES

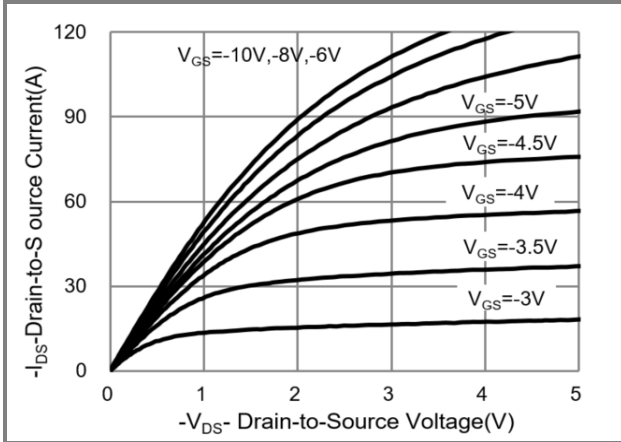


Fig.1 On-Region Characteristics

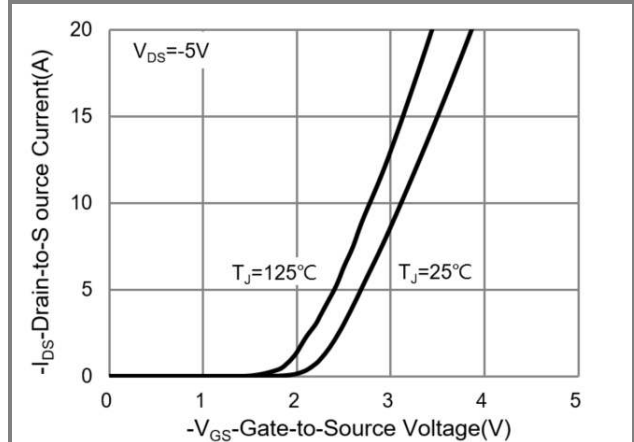


Fig.2 Transfer Characteristics

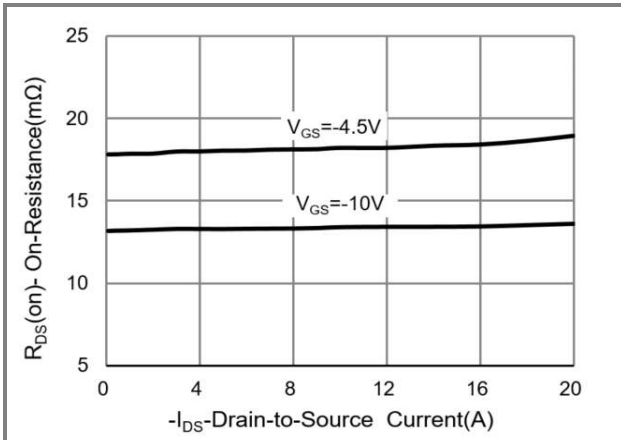


Fig.3 On-Resistance vs. Drain Current

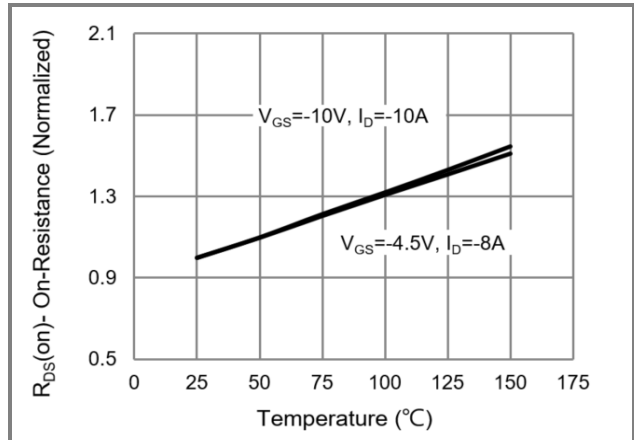


Fig.4 On-Resistance vs. Junction temperature

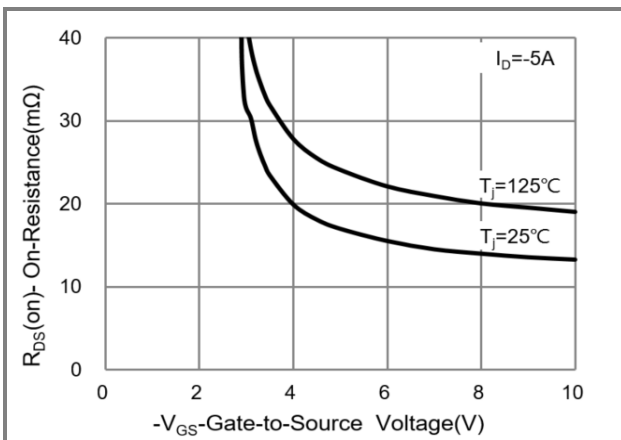


Fig.5 On-Resistance Variation with V_{GS}

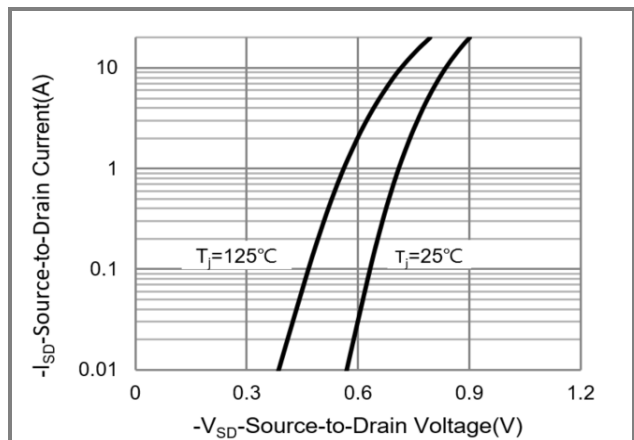


Fig.6 Source-Drain Diode Forward Voltage



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TYPICAL CHARACTERISTIC CURVES

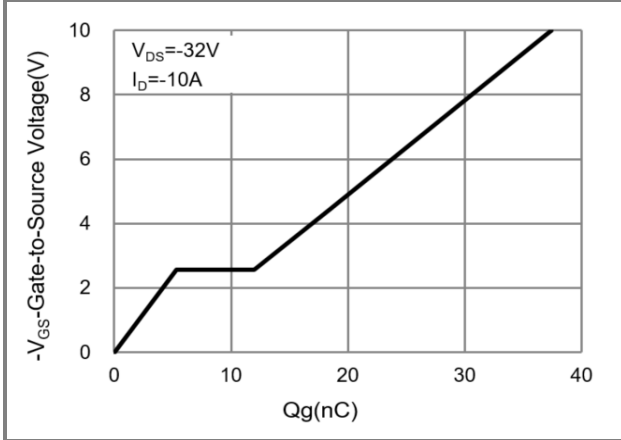


Fig.7 Gate-Charge Characteristics

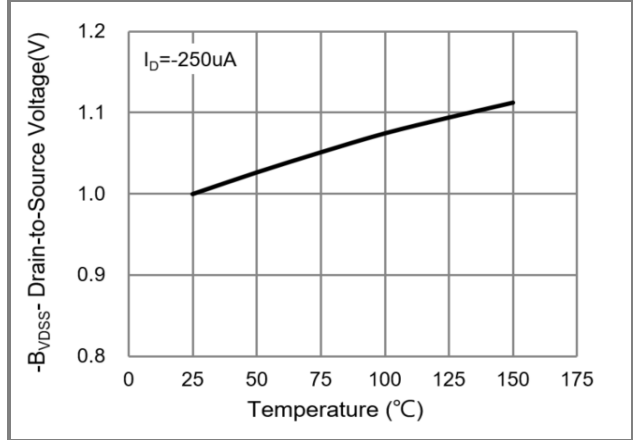


Fig.8 Breakdown Voltage Variation vs. Temperature

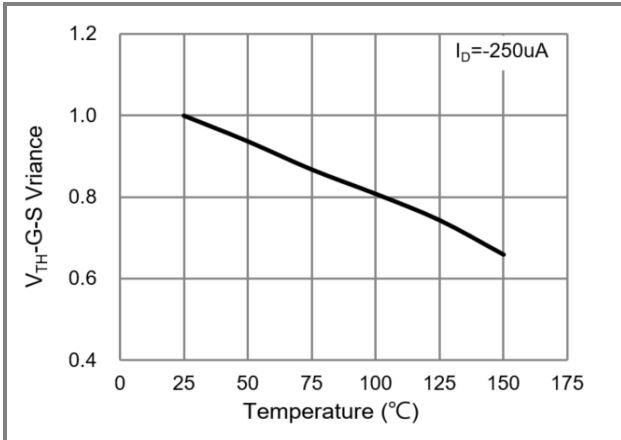


Fig.9 Threshold Voltage Variation with Temperature

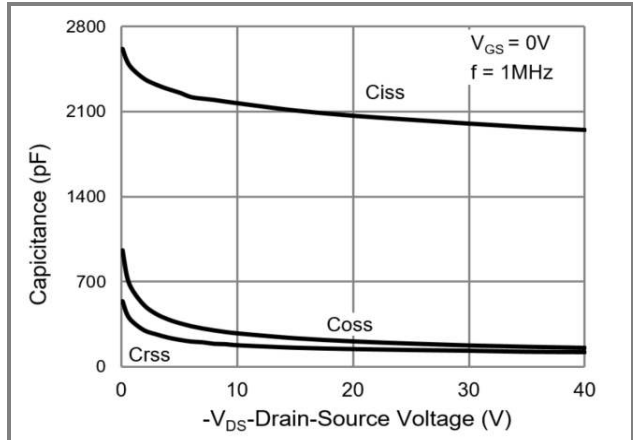


Fig.10 Capacitance vs. Drain-Source Voltage

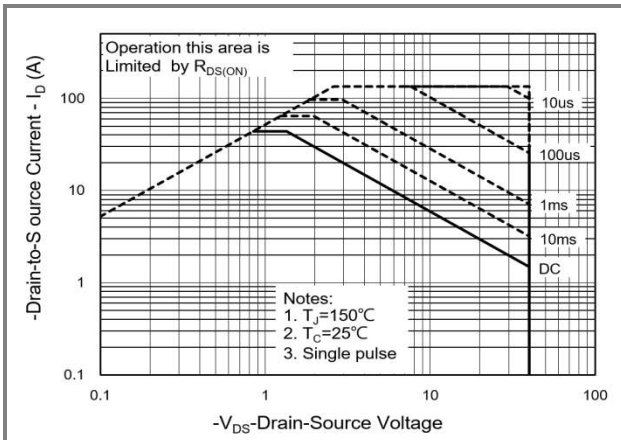


Fig.11 Maximum Safe Operating Area

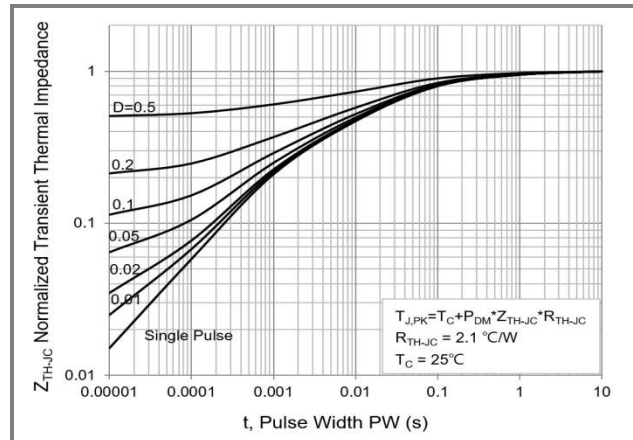


Fig.12 Normalized Transient Thermal Impedance

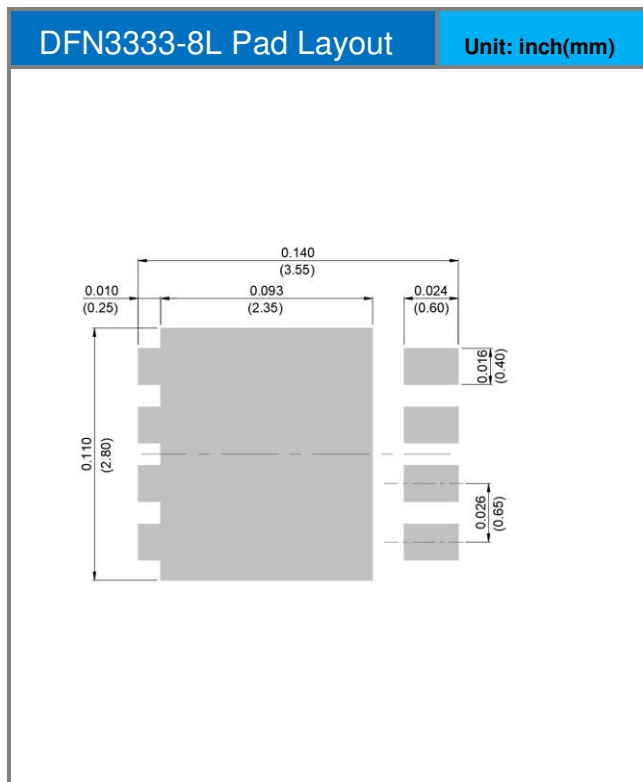
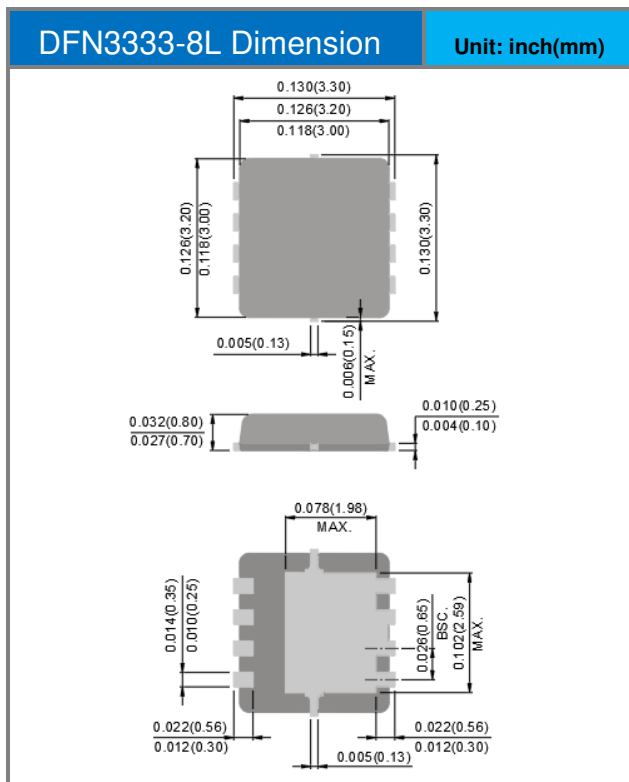


PJQ4441P-AU

Part No. Packing Code Version

| Part No. Packing Code | Package Type | Packing Type | Marking | Version |
|-----------------------|--------------|-------------------|---------|--------------------------------|
| PJQ4441P-AU_R2_000A1 | DFN3333-8L | 5K pcs / 13" reel | 4441 | Halogen free RoHS compliant |

Packaging Information & Mounting Pad Layout





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